TOSHIBA Field Effect Transistor Silicon P Channel MOS Type

SSM6P16FE

High Speed Switching Applications

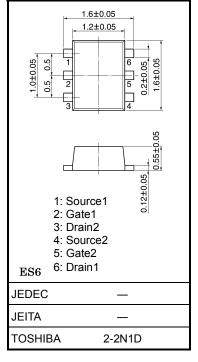
Analog Switch Applications

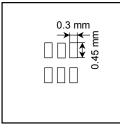
- Small package
- Low on-resistance $: R_{on} = 8 \Omega \pmod{(max)} (@V_{GS} = -4 V)$
 - : Ron = 12 Ω (max) (@VGS = -2.5 V)
 - : $R_{on} = 45 \Omega \text{ (max)} (@V_{GS} = -1.5 \text{ V})$

Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

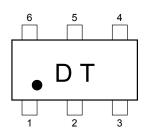
Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V _{DS}	-20	V	
Gate-Source voltage		V _{GSS}	±10	V	
Drain current	DC	۱ _D	-100	mA	
	Pulse	I _{DP}	-200		
Drain power dissipation (Ta = 25° C)		P _D (Note)	150	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

Note: Total rating, mounted on FR4 board (25.4 mm \times 25.4 mm \times 1.6 t, Cu Pad: 0.135 mm $^2 \times$ 6)

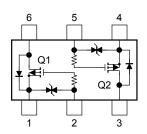




Marking



Equivalent Circuit (top view)



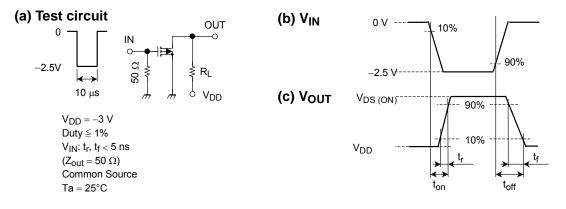
Handling Precaution

When handling individual devices (which are not yet mounted on a circuit board), ensure that the environment is protected against static electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristic		Symbol	Test Condition	MIN.	TYP.	MAX.	UNIT
Gate leakage current		I _{GSS}	$V_{GS}=\pm 10~V,~V_{DS}=0$			±1	μA
Drain-Source breakdown voltage		V (BR) DSS	$I_D = -0.1 \text{ mA}, V_{GS} = 0$	-20			V
Drain cut-off current		I _{DSS}	$V_{DS} = -20 V, V_{GS} = 0$	_		-1	μA
Gate threshold voltage		V _{th}	$V_{DS} = -3 \text{ V}, \text{ I}_{D} = -0.1 \text{ mA}$	-0.6	_	-1.1	V
Forward transfer admittance		Y _{fs}	$V_{DS} = -3 \text{ V}, \text{ I}_{D} = -10 \text{ mA}$	25			mS
Drain-Source on-resistance		R _{DS (ON)}	$I_D = -10 \text{ mA}, V_{GS} = -4 \text{ V}$		6	8	Ω
			$I_D = -10$ mA, $V_{GS} = -2.5$ V		8	12	
			$I_D = -1 \text{ mA}, V_{GS} = -1.5 \text{ V}$	_	18	45	
Input capacitance		C _{iss}			11	_	pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = -3 V$, $V_{GS} = 0$, f = 1 MHz		3.7		pF
Output capacitance		C _{oss}	1		10		pF
Switching time	Turn-on time	t _{on}	$V_{DD} = -3 V$, $I_{D} = -10 mA$,		130		ns
	Turn-off time	t _{off}	$V_{GS} = 0 \sim -2.5 V$		190		

Switching Time Test Circuit

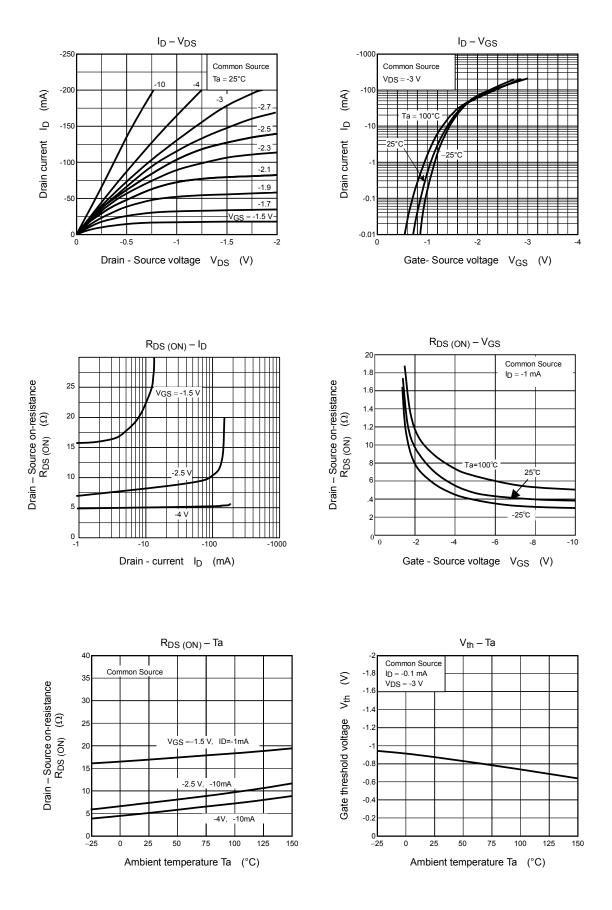


Precaution

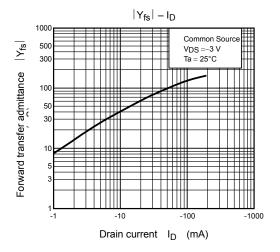
 V_{th} can be expressed as the voltage between the gate and source when the low operating current value is ID = 100 μ A for this product. For normal switching operation, VGS (on) requires a higher voltage than Vth and VGS (off) requires a lower voltage than Vth. (The relationship can be established as follows: VGS (off) < Vth < VGS (on).)

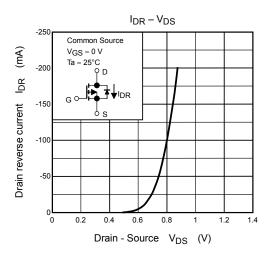
Be sure to take this into consideration when using the device. The $V_{\rm GS}$ recommended voltage for turning on this product is -1.5V or higher.

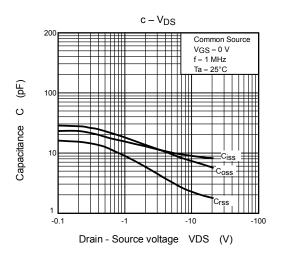
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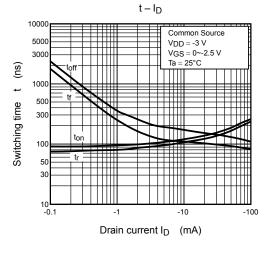


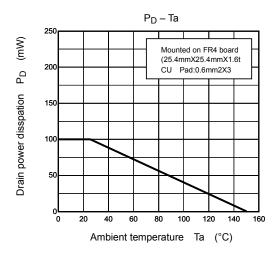
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